

1.5V Drive Pch+Pch MOSFET

US6J11

●Structure

Silicon P-channel MOSFET

Features

- 1) Two Pch MOSFET transistors in a single TUMT6 package.
- 2) Mounting cost and area can be cut in half.
- 3) Low on-resistance.
- 4) Low voltage drive (1.5V) makes this device ideal for portable equipment.
- 5) Drive circuits can be simple.

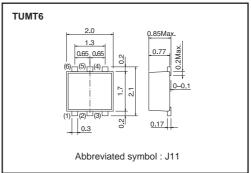
Application

Switching

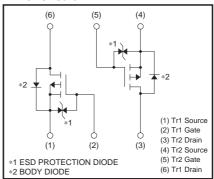
Packaging specifications

	Package	Taping
Type	Code	TR
	Basic ordering unit (pieces)	3000
US6J11		0

●Dimensions (Unit : mm)



●Inner circuit



●Absolute maximum ratings (Ta=25°C)

Parameter		Symbol	Limits	Unit	
Drain-source voltage		V _{DSS}	-12	V	
Gate-source voltage		Vgss	±10	V	
Drain current	Continuous	ID	±1.3	А	
Drain current	Pulsed	I _{DP} *1	±5.2	А	
Source current	Continuous	Is	-0.5	А	
(Body diode)	Pulsed	I _{SP} *1	-5.2	A	
Total power dissipation		P _D *2	1.0	W / TOTAL	
		10 -	0.7	W / ELEMENT	
Channel temperature		Tch	150	°C	
Range of Storage temperature		Tstg	-55 to +150	°C	

Thermal resistance

Parameter	Symbol	Limits	Unit
Channel to ambient	Pth/oh o*	125	°C/W / TOTAL
Charmer to ambient	Rth(ch-a)	179	°C/W / ELEMENT

^{*} When mounted on a ceramic board

^{*1} Pw≤10µs, Duty cycle≤1% *2 When mounted on a ceramic board

US6J11 Data Sheet

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions	
Gate-source leakage	I _{GSS}	_	-	±10	μА	V _{GS} =±10V, V _{DS} =0V	
Drain-source breakdown voltage	V _(BR) DSS	-12	-	_	V	I _D = -1mA, V _{GS} =0V	
Zero gate voltage drain current	IDSS	_	_	-1	μΑ	V _{DS} = -12V, V _{GS} =0V	
Gate threshold voltage	VGS (th)	-0.3	_	-1.0	V	V _{DS} = -6V, I _D = -1mA	
		-	190	260	mΩ	I _D = -1.3A, V _G S= -4.5V	
Static drain-source on-state	Page .*	_	280	390	mΩ	$I_D = -0.6A$, $V_{GS} = -2.5V$	
resistance	R _{DS} (on)	_	400	600	mΩ	I _D = -0.6A, V _G S= -1.8V	
		_	530	1060	mΩ	I _D = -0.2A, V _G S= -1.5V	
Forward transfer admittance	Yfs *	1.4	_	_	S	V _{DS} = -6V, I _D = -1.3A	
Input capacitance	Ciss	_	290	_	pF	V _{DS} = -6V	
Output capacitance	Coss	_	28	_	pF	V _{GS} =0V	
Reverse transfer capacitance	Crss	_	21	_	pF	f=1MHz	
Turn-on delay time	td (on) *	_	8	_	nS	Vpp≒-6V	
Rise time	tr *	_	10	_	nS	ID= -0.6A	
Turn-off delay time	t _{d (off)} *	_	30	_	nS	Vgs= -4.5V Ri≒10Ω	
Fall time	t _f *	_	9	_	nS	R _G =10Ω	
Total gate charge	Qg *	_	2.4	-	nC	V _{DD} ≒−6V R _L =4.6Ω	
Gate-source charge	Q _{gs} *	_	0.6	-	nC	I _D =-1.3A R _G =10Ω	
Gate-drain charge	Q _{gd} *	_	0.4	_	nC	Vgs=-4.5V	

^{*} Pulsed

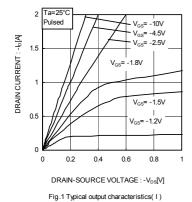
●Body diode characteristics (Source-drain) (Ta=25°C)

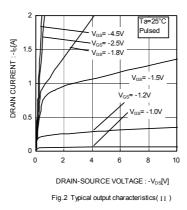
Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Forward voltage	Vsp *	_	_	-1.2	V	I _S = -1.3A, V _{GS} =0V

^{*} Pulsed

US6J11 Data Sheet

•Electrical characteristics curves





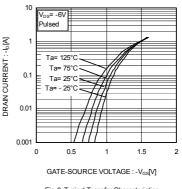
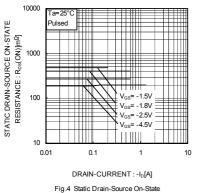


Fig.3 Typical Transfer Characteristics



Resistance vs. Drain Current(I)

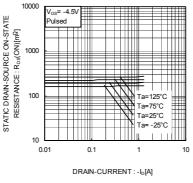


Fig.5 Static Drain-Source On-State Resistance vs. Drain Current(II)

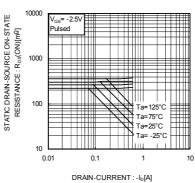


Fig.6 Static Drain-Source On-State Resistance vs. Drain Current(III)

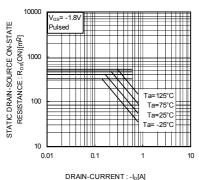


Fig.7 Static Drain-Source On-State Resistance vs. Drain Current(IV)

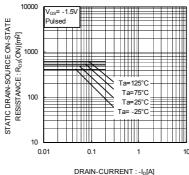


Fig.8 Static Drain-Source On-State Resistance vs. Drain Current(V)

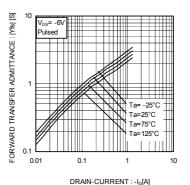
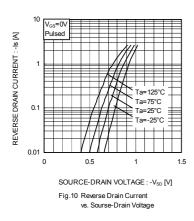
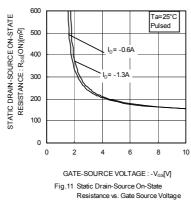


Fig.9 Forward Transfer Admittance vs. Drain Current





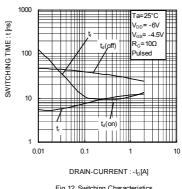
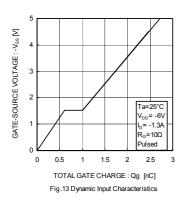
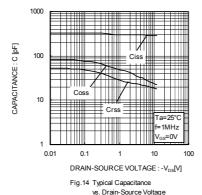


Fig.12 Switching Characteristics





●Measurement circuits

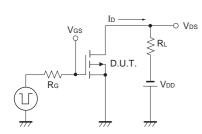


Fig.1-1 Switching time measurement circuit

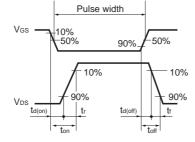


Fig.1-2 Switching waveforms

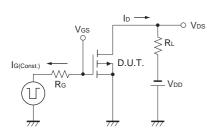


Fig.2-1 Gate charge measurement circuit

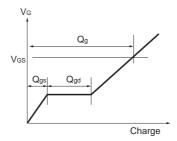


Fig.2-2 Gate charge waveform

Notice

This product might cause chip aging and breakdown under the large electrified environment. Please consider to design ESD protection circuit.

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